

Features: (typical values)

- High IP3 +52.0 dBm.
- High Gain + 24 dB
- High Output Power +36.0 dBm.
- Low cost

Maximum Ratings

Storage Temperature -40°C to +125°C
 DC Voltage +12 volts
 RF Input Power +5 dBm.
 Case Temperature +95°C

2000-2200 MHz Ultra Linear 4 Watts Amplifier



Electrical Specifications (Referenced to 50 ohms)

Parameter	Typical Conditions	Min Value	Max Value	Units
Frequency		2000	2200	MHz.
Gain	24.0	22.0		dB.
Gain Flatness	±0.4		+1.0	dB.
Reverse Isolation	40			dB.
Pout @ 1dB Comp	36.0	35.0		dBm.
Noise Figure	3.0		5.0	dB.
VSWR (Input/Output)	1.8/1.9		2:1/2.5:1	dBm.
IP3 (two-tone)	+51.0	+50.0		
Supply Required	+10/1400		+10/1600	v/mA.

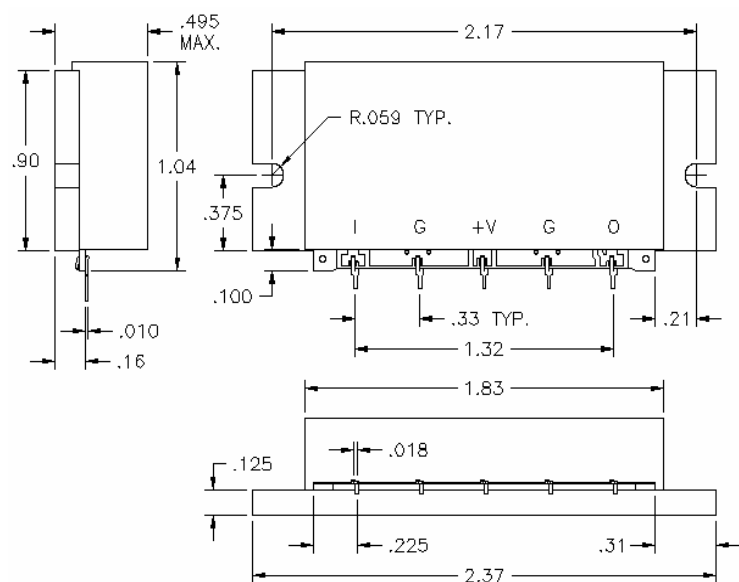
IP3 measured with 2 tones @+22dBm. per tone

Min and max values from 0 to 70 degrees C

Require 10uF at Vcc line.

Pin Configuration

Pin #	Description
1	Input
2,4	Ground
3	Vcc
5	Output



Typical Performance Curves @ 25°C

